# **CNA1006N**

### Photo Interrupter

For contactless SW and object detection

#### Overview

CNA1006N is a transmissive photosensor in which a high efficiency GaAs infrared light emitting diode is used as the light emitting element, and a high sensitivity phototransistor is used as the light detecting element. The two elements are arranged so as to face each other, and objects passing between them are detected.

#### ■ Features

- Highly precise position detection: 0.3 mm
- Gap width: 3 mm
- The type directly attached to PCB (with a positioning pins)

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

| F                            | Symbol                                | Rating           | Unit |      |  |
|------------------------------|---------------------------------------|------------------|------|------|--|
| Input (Light emitting diode) | Power dissipation *1                  | $P_{\mathrm{D}}$ | 75   | mW   |  |
|                              | Forward current                       | $I_{\mathrm{F}}$ | 50   | mA   |  |
|                              | Reverse voltage                       | $V_R$            | 3    | V    |  |
| Output (Photo transistor)    | Collector-emitter voltage (Base open) | V <sub>CEO</sub> | 30   | O'VO |  |
|                              | Emitter-collector voltage (Base open) | $V_{ECO}$        | 5    | v    |  |
|                              | Collector current                     | $I_{\rm C}$      | 20   | mA   |  |
|                              | Collector power dissipation *2        | $P_{\rm C}$      | 100  | mW   |  |
| Operating ambient temp       | T <sub>opr</sub>                      | -25 to +85       | 0° ℃ |      |  |
| Storage temperature          | $T_{stg}$                             | -40 to +100      | °C   |      |  |

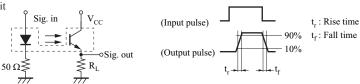
Note) \*1: Input power derating ratio is 1.0 mW/°C at  $T_a \ge 25$ °C.

#### ■ Electrical-Optical Characteristics $T_a = 25$ °C±3°C

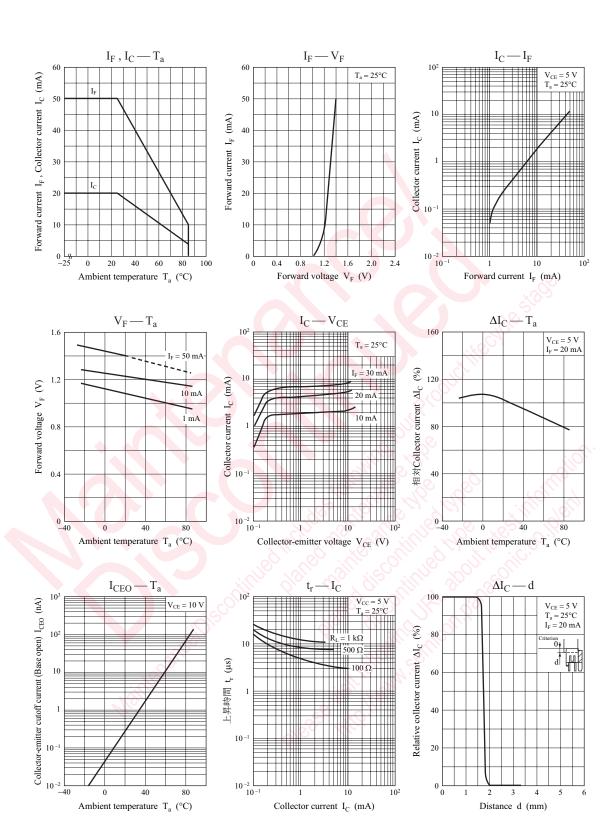
| Parameter                |  | Symbol               | Conditions   | Min | Тур  | Max  | Unit |
|--------------------------|--|----------------------|--|-----|------|------|------|
| Input characteristics    | Reverse current                              | $I_R$                | $V_R = 3 V$  |     |      | 10   | μΑ   |
|                          | Forward voltage                              | V <sub>F</sub>       | $I_F = 20 \text{ mA}$  |     | 1.25 | 1.4  | V    |
| Output characteristics   | Collector-emitter cutoff current (Base open) | I <sub>CEO</sub>     | $V_{CE} = 10 \text{ V}$  |     | 10   | 200  | nA   |
| Transfer characteristics | Collector current                            | $I_{\rm C}$          | $V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}$                    | 0.7 |      | 14.0 | mA   |
|                          | Collector-emitter saturation voltage         | V <sub>CE(sat)</sub> | $I_F = 40 \text{ mA}, I_C = 1 \text{ mA}$                      |     |      | 0.4  | V    |
|                          | Rise time *                                  | t <sub>r</sub>       | $V_{CC} = 5 \text{ V}, I_C = 1 \text{ mA},$ $R_L = 100 \Omega$ |     | 5.0  |      | μs   |
|                          | Fall time *                                  | $t_{\mathrm{f}}$     |  |     | 5.0  |      | μs   |

Note) 1. Input and output are practiced by electricity.

- 2. This device is designed by disregarding radiation.
- 3. \*: Switching time measurement circuit



<sup>\*2:</sup> Output power derating ratio is 1.33 mW/°C at  $T_a \ge 25$ °C.

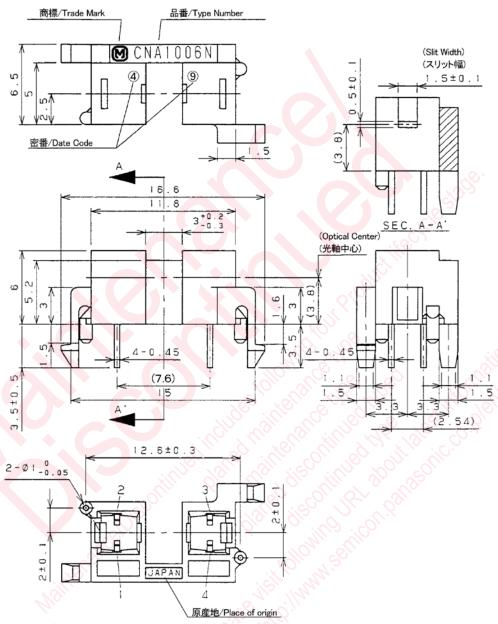


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#### ■ Package (Unit: mm)

## LSSSIR4S0006



(注 1)(Note1)指示無き寸法公差: ±0.3/Not appointment tolerance: ±0.3 (注 2)(Note2)嵌合強度: 2N 以上(静止荷重)/Fitting strength: 2 N Min. (Static load) (注 3) マークは、目視又は顕微鏡に於いて解読できる事

(Note3)What a mark sees an attention and can decode in a microscope.

- Pin name
  - 1: Anode
  - 2: Cathode
  - 3: Collector
  - 4: Emitter

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